I hereby certify that this correspondence being deposited with the Uni 20231, on

- 1 -

Docket: 0756-958

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT application of

Shunpei YAMAZAKI, et al.

Serial No. 08/183,800

Filed: January 21, 1994

SEMICONDUCTOR MATERIAL For:

AND METHOD FOR FORMING

THE SAME AND THIN FILM

**TRANSISTOR** 

) Art Unit: 2508

Examiner: M. Saadat
RECEIVED

Date: April 30, 1996

AMENDMENT AND SUBMISSION OF SUBSTITUTE DECLARATION

Honorable Assistant Commissioner for Patents

Washington, D.C. 20231

Sir:

Please amend the subject application as follows:

## IN THE SPECIFICATION:

Please delete the first sentence of the subject application as stated at paragraph 5 of the Request dated January 21,1 994, for filing the subject continuation application. In place of the foregoing deleted first sentence, please insert the following sentence: